

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain Source Voltage		Vdss	50	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current (Note 5)	Continuous	lD	280	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient	Reja	833	°C/W
Operating and Storage Temperature Range	Tj, Tstg	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

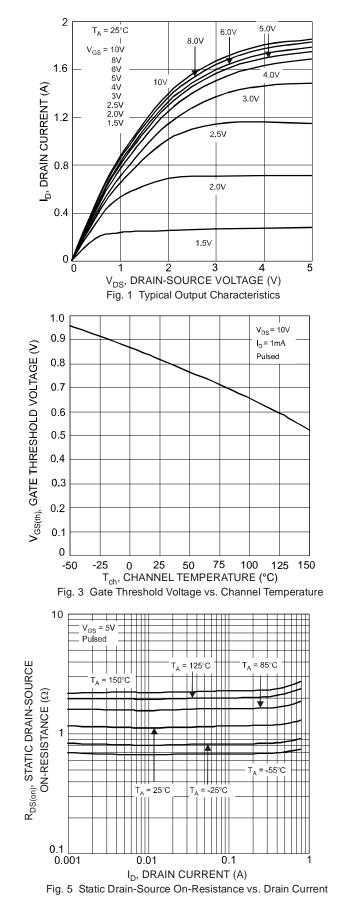
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)								
Drain-Source Breakdown Voltage		BVDSS	50	_		V	$V_{GS} = 0V, I_{D} = 10\mu A$	
Zero Gate Voltage Drain Current	@ T _C = +25°C	IDSS			60	nA	$V_{DS} = 50V, V_{GS} = 0V$	
Gate-Body Leakage		lgss	_	_	1 500 50	μA nA nA	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)								
Gate Threshold Voltage		V _{GS(TH)}	0.49	—	1.2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		Rds(on)		1.8 1.5 1.2	3.0 2.5 2.0	Ω	$V_{GS} = 1.8V, I_D = 50mA$ $V_{GS} = 2.5V, I_D = 50mA$ $V_{GS} = 5.0V, I_D = 50mA$	
On-State Drain Current		ID(ON)	0.5	1.4		А	Vgs = 10V, Vds = 7.5V	
Forward Transconductance		Y _{fs}	200	_		ms	V _{DS} =10V, I _D = 0.2A	
Source-Drain Diode Forward Voltage		Vsd	0.5	_	1.4	V	Vgs = 0V, Is = 115mA	
DYNAMIC CHARACTERISTICS								
Input Capacitance		Ciss	—		50	pF		
Output Capacitance		Coss	_		25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance		Crss	_	_	5.0	pF		

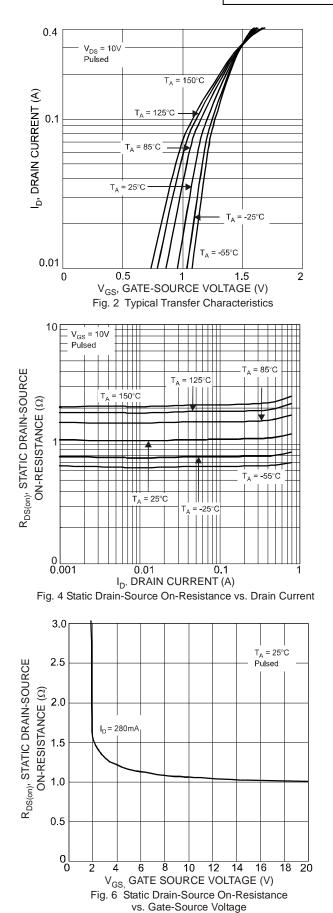
Notes: 5. Device mounted on FR-4 PCB.

6. Short duration pulse test used to minimize self-heating effect.

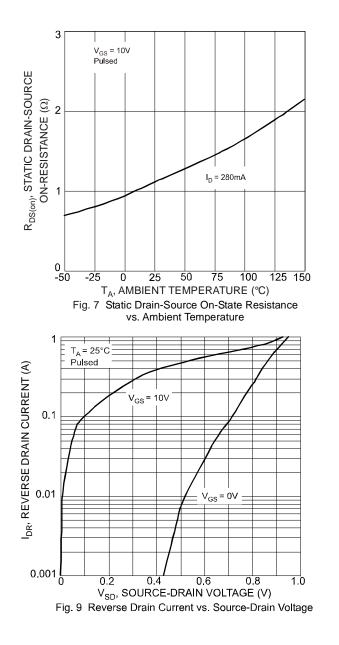


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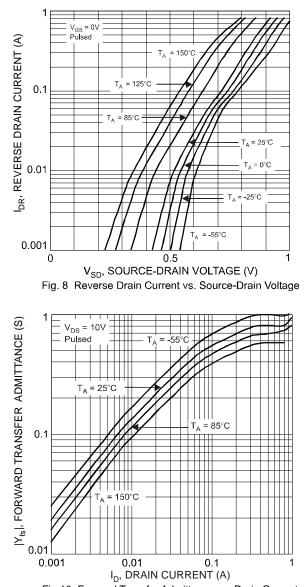
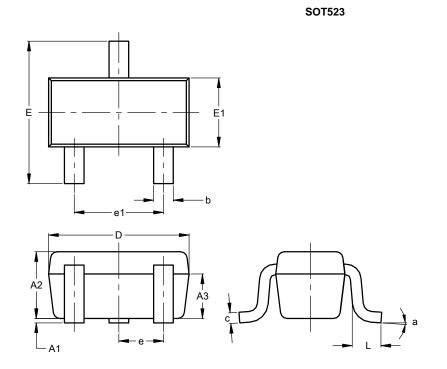


Fig.10 Forward Transfer Admittance vs. Drain Current



Package Outline Dimensions

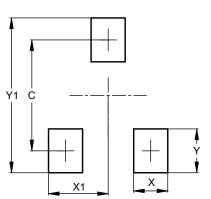
Please see http://www.diodes.com/package-outlines.html for the latest version.



1						
SOT523						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.60	0.80	0.75			
A3	0.45	0.65	0.50			
b	0.15	0.30	0.22			
C	0.10	0.20	0.12			
D	1.50	1.70	1.60			
Е	1.45	1.75	1.60			
E1	0.75	0.85	0.80			
е	0.50 BSC					
e1	0.90	1.10	1.00			
L	0.20	0.40	0.33			
а	0°		8°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80

SOT523



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